

DESCRIPTION

The SPN4910 is the Dual N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

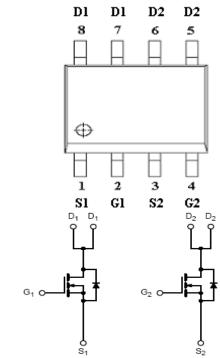
FEATURES

- ♦ N-Channel 40V/10A,RDS(ON)= $20m\Omega@VGS$ =10V 40V/8A,RDS(ON)= $24m\Omega@VGS$ =4.5V 40V/6A,RDS(ON)= $30m\Omega@VGS$ =2.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOP-8 package design

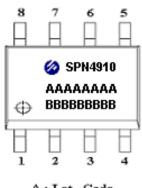
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

PIN CONFIGURATION(SOP-8)



PART MARKING



A: Lot Code B: Date Code

IN DESCRIPTION						
Pin	Symbol	Description				
1	S 1	Source 1				
2	G1	Gate 1				
3	S2	Source 2				
4	G2	Gate 2				
5	D2	Drain 2				
6	D2	Drain 2				
7	D1	Drain 1				
8	D1	Drain 1				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN4910S8RGB	SOP-8	SPN4910

[※] SPN4910S8RGB 13" Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

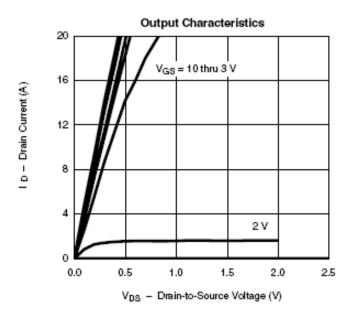
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	40	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Drain Current(T _J =150°C)	Ta=25°C	ID	10.0	A	
	Ta=70°C		8.0		
Pulsed Drain Current		Idm	25	A	
Continuous Source Current(Diode Conduction)		Is	2.3	A	
	Ta=25°C	PD	2.5	W	
Power Dissipation	Ta=70°C		1.6		
Operating Junction Temperature		Тл	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient	$\frac{T \le 10 sec}{Steady State}$	R _θ JA	50 80	°C/W	

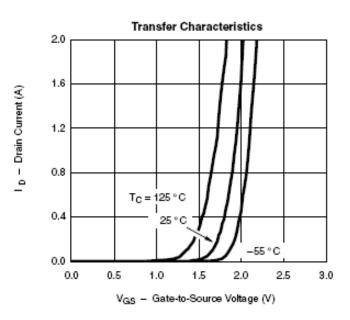
ELECTRICAL CHARACTERISTICS

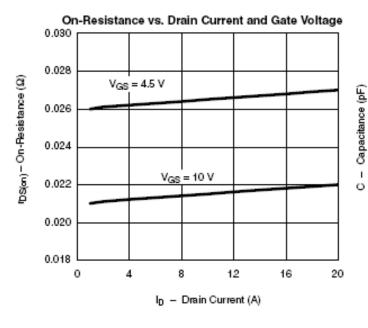
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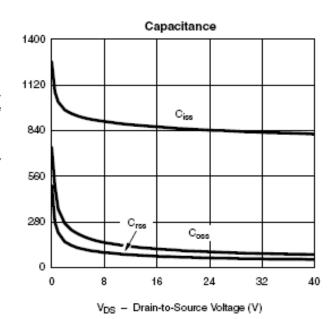
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static		1	L	1	ı		
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	40			V	
Gate Threshold Voltage	VGS(th)	$V_{DS}=V_{GS}$, $V_{DS}=V_{CS}$, V_{D			1.0	\ \ \ \	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
Zero Gate Voltage Drain Current		VDS=40V,VGS=0V			1	uA	
	Idss	V _{DS} =40V,V _{GS} =0V T _J =85°C			10		
On-State Drain Current	ID(on)	$V_{DS} = 5V, V_{GS} = 4.5V$	10			A	
		Vgs=10V,Id=10A		0.014	0.020		
Drain-Source On-Resistance	RDS(on)	Vgs=4.5V,Id=8A		0.017	0.024	Ω	
		Vgs=2.5V,Id=6A		0.024	0.030		
Forward Transconductance	gfs	VDS=15V,ID=6.2A		13		S	
Diode Forward Voltage	Vsd	Is=2.3A,VGS =0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg			10	14	nC	
Gate-Source Charge	Qgs	V _{DS} =20V,V _{GS} =4.5V I _D =5A		2.8			
Gate-Drain Charge	Qgd	ID-JA		3.2			
Input Capacitance	Ciss			850		pF	
Output Capacitance	Coss	VDS=20V,VGS=0V f=1MHz		110			
Reverse Transfer Capacitance	Crss			75			
Turn-On Time	td(on)			6	12	nS	
	tr	VDD=20V,RL=4 Ω		10	20		
Turn-Off Time	td(off)	$I_{D=5.0A,VGEN=10V}$ $R_{G=1}\Omega$		20	36		
	tf			6	12		

TYPICAL CHARACTERISTICS

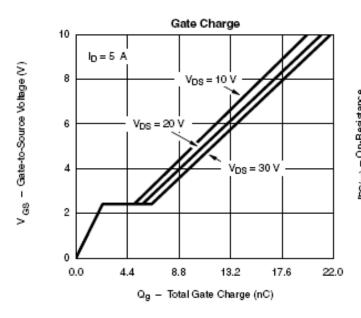


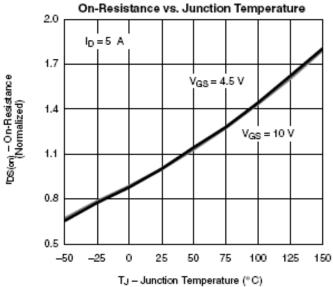


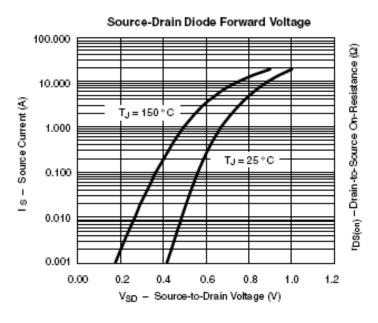


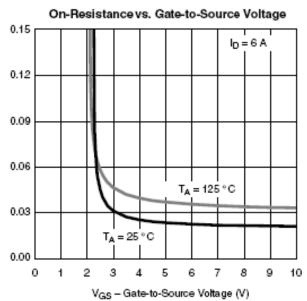


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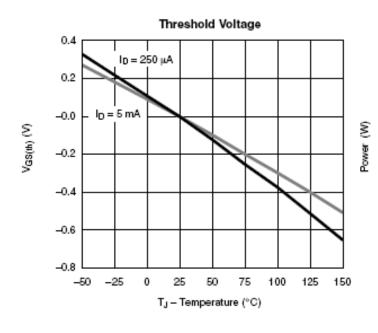


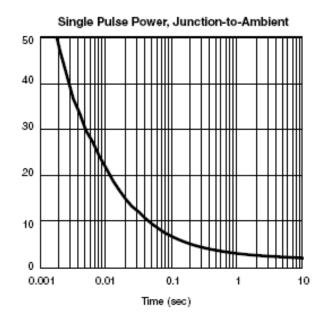


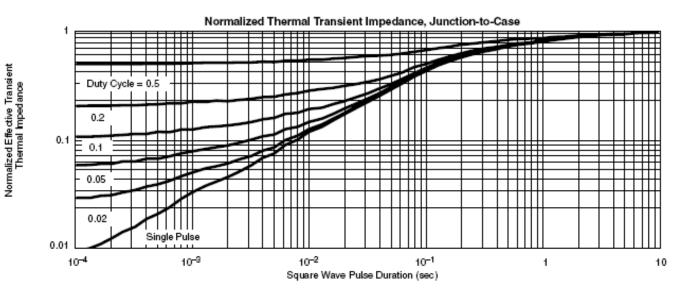




TYPICAL CHARACTERISTICS







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